

TOSHIBA Photocoupler GaAs Ired & Photo-Transistor

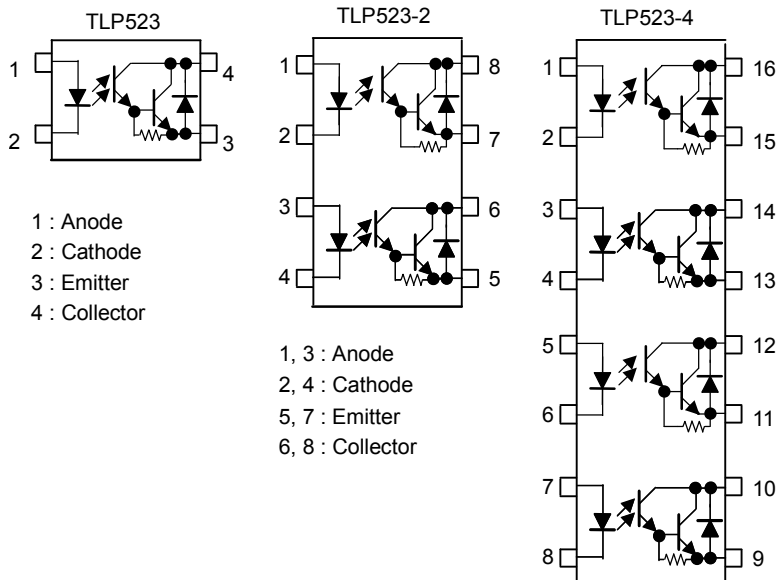
TLP523, TLP523-2, TLP523-4

Programmable Controllers
DC-Output Module
Solid State Relay

The TOSHIBA TLP523, -2 and -4 consists of a gallium arsenide infrared emitting diode coupled with a silicon, darlington connected, phototransistor which has an integral base-emitter resistor to optimize switching speed and elevated temperature characteristics. The TLP523-2 offers two isolated channels in an eight lead plastic DIP package, while the TLP523-4 provide four isolated channels per package.

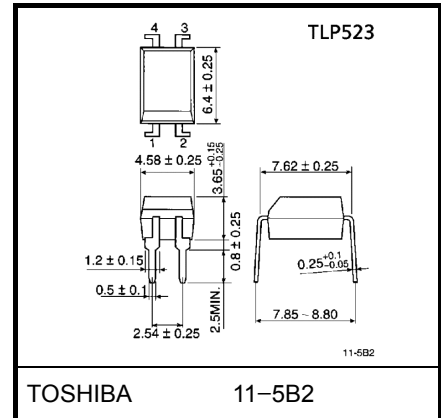
- Current transfer ratio: 500% (min.) ($I_F = 1 \text{ mA}$)
- Isolation voltage: 2500 Vrms (min.)
- Collector-emitter voltage: 55 V (min.)
- Leakage current: 10 μA (max.) ($T_a = 85^\circ\text{C}$)
- UL recognized: UL1577, file no. E67349

Pin Configurations (top view)

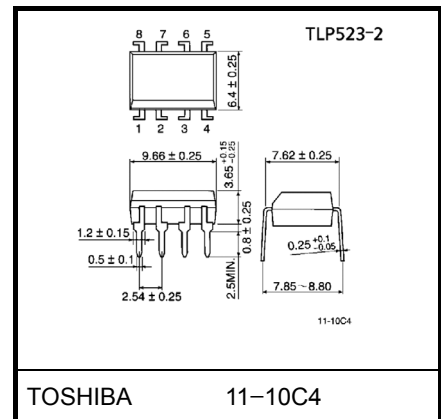


1, 3, 5, 7 : Anode
2, 4, 6, 8 : Cathode
9, 11, 13, 15 : Emitter
10, 12, 14, 16: Collector

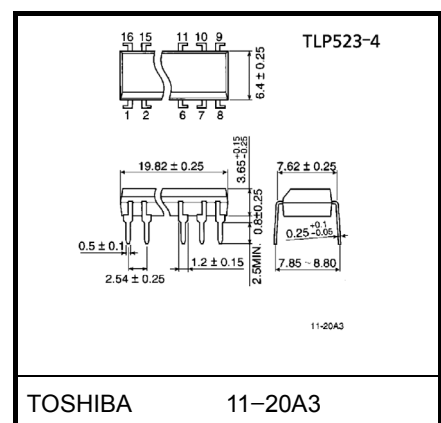
Unit in mm



TOSHIBA 11-5B2
Weight: 0.26 g



TOSHIBA 11-10C4
Weight: 0.54 g



TOSHIBA 11-20A3
Weight: 1.1 g

Absolute Maximum Ratings (Ta = 25°C)

Characteristic	Symbol	Rating		Unit	
		TLP523	TLP523-2 TLP523-4		
LED	Forward current	I _F	60	50	mA
	Forward current derating	ΔI _F /°C	-0.7 (Ta ≥ 39°C)	-0.5 (Ta ≥ 25°C)	mA /°C
	Pulse forward current	I _{FP}	1 (100μs pulse, 100pps)		A
	Reverse voltage	V _R	5		V
Detector	Collector-emitter voltage	V _{CEO}	55		V
	Emitter-collector voltage	V _{ECO}	0.3		V
	Collector current	I _C	150		mA
	Collector power dissipation (1 circuit)	P _C	150	100	mW
	Collector power dissipation derating (1 circuit (Ta ≥ 25°C))	ΔP _C /°C	-1.5	-1.0	mW /°C
	Operating temperature range	T _{opr}	-55~100		°C
Storage temperature range	T _{stg}	-55~125		°C	
Lead soldering temperature (10 s)	T _{sol}	260		°C	
Total power dissipation	P _T	250	150	mW	
Total power dissipation derating (Ta ≥ 25°C)	ΔP _T /°C	-2.5	-1.5	mW /°C	
Isolation voltage (Note 1)	BV _S	2500 (AC, 1min., R.H.≤ 60%)		V _{rms}	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Device considered a two terminal device: LED side pins shorted together and detector side pins shorted together.

Recommended Operating Conditions

Characteristic	Symbol	Min.	Typ.	Max.	Unit
Supply voltage	V _{CC}	—	5	24	V
Forward current	I _F	—	16	20	mA
Operating temperature range	T _{opr}	-25	—	85	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

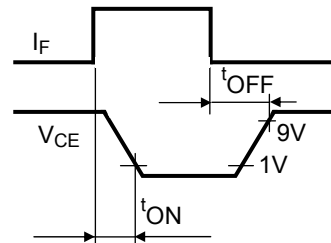
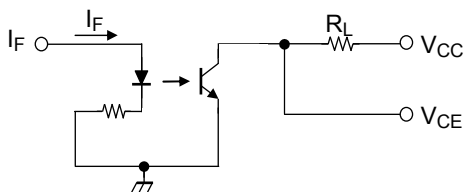
Electrical Characteristics (Ta = 25°C)

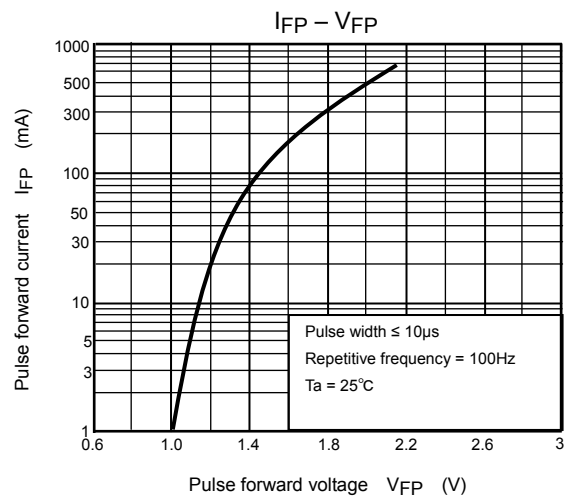
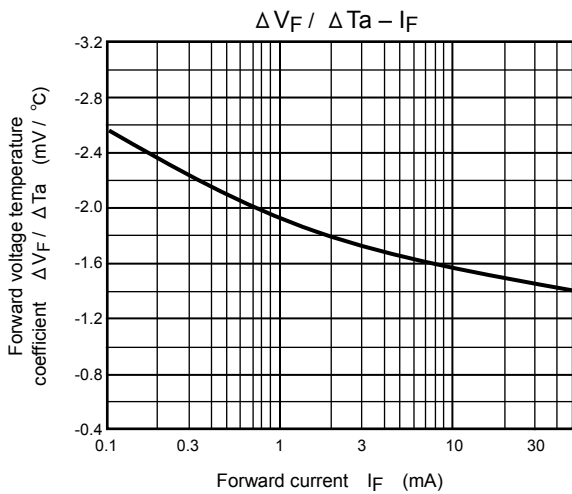
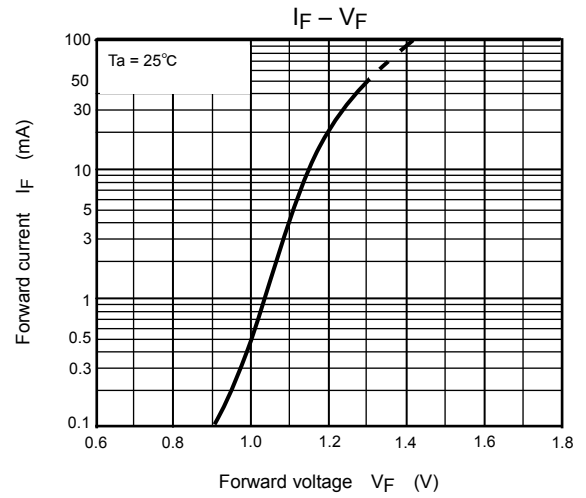
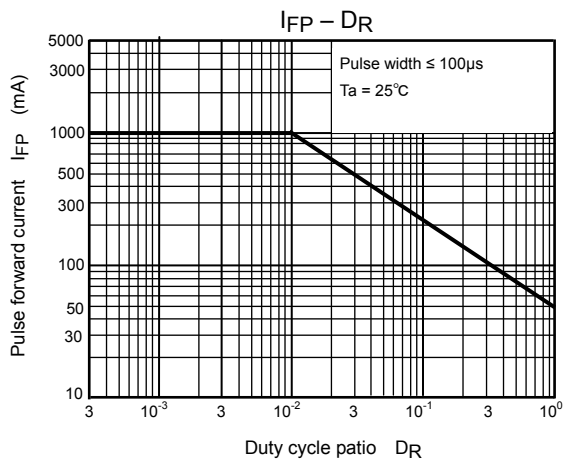
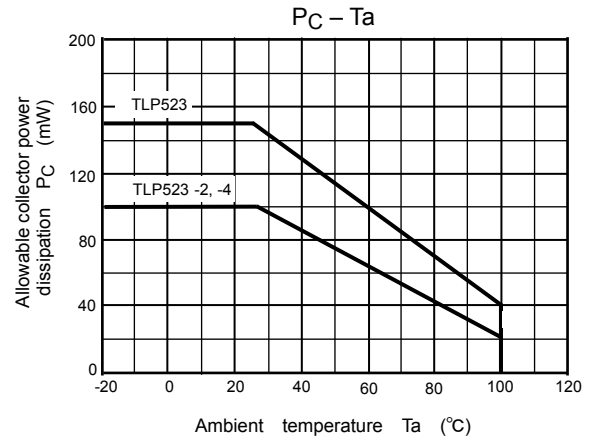
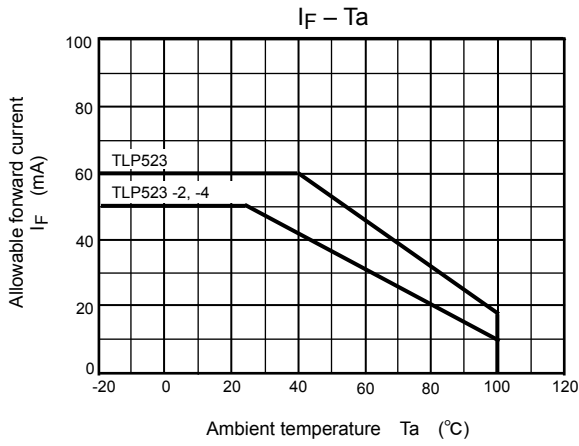
Characteristic		Symbol	Test Condition	Min.	Typ.	Max.	Unit
LED	Forward voltage	V_F	$I_F = 10 \text{ mA}$	1.0	1.15	1.3	V
	Reverse current	I_R	$V_R = 5 \text{ V}$	—	—	10	μA
	Capacitance	C_T	$V = 0, f = 1 \text{ MHz}$	—	30	—	pF
Detector	Collector-emitter breakdown voltage	$V_{(BR)CEO}$	$I_C = 1 \text{ mA}$	55	—	—	V
	Collector dark current	I_{CEO}	$V_{CE} = 24 \text{ V}$	—	10	200	nA
			$V_{CE} = 24 \text{ V}, T_a = 85^\circ\text{C}$	—	0.5	10	μA
Capacitance collector to emitter	C_{CE}	$V = 0, f = 1 \text{ MHz}$	—	10	—	pF	
Coupled	Current transfer ratio	I_C / I_F	$I_F = 1 \text{ mA}, V_{CE} = 1 \text{ V}$	500	2000	—	%
	Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C = 50 \text{ mA}, I_F = 10 \text{ mA}$	—	—	1	V
	Capacitance input to output	C_S	$V_S = 0, f = 1 \text{ MHz}$	—	0.8	—	pF
	Isolation resistance	R_S	$V_S = 500 \text{ V}, \text{R.H.} \leq 60\%$	5×10^{10}	10^{14}	—	Ω

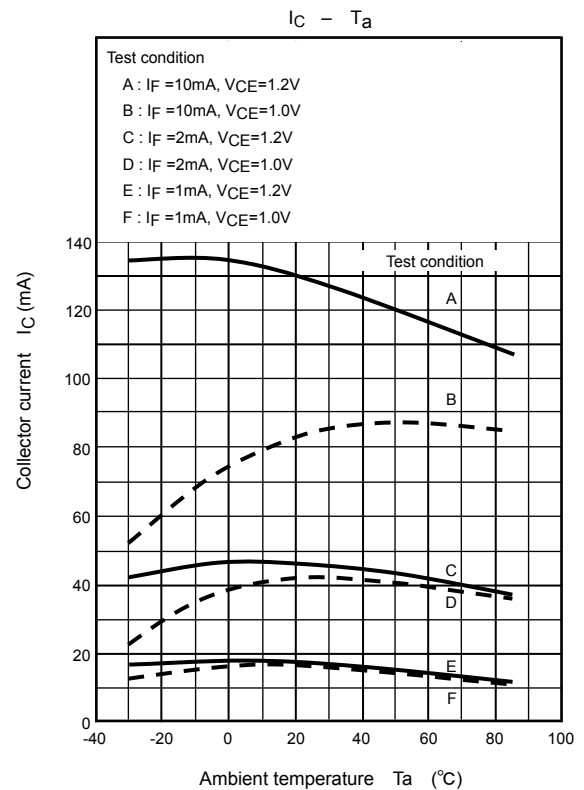
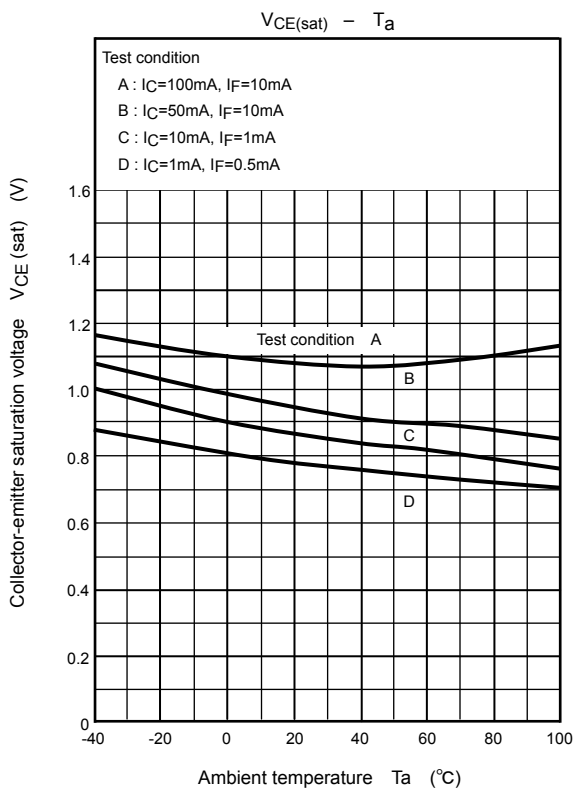
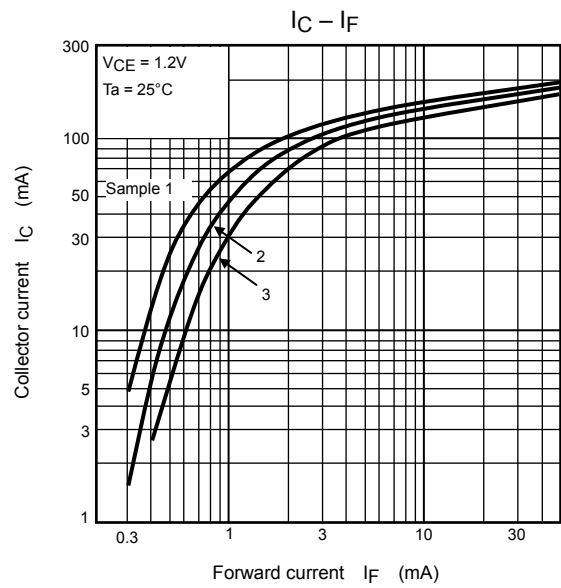
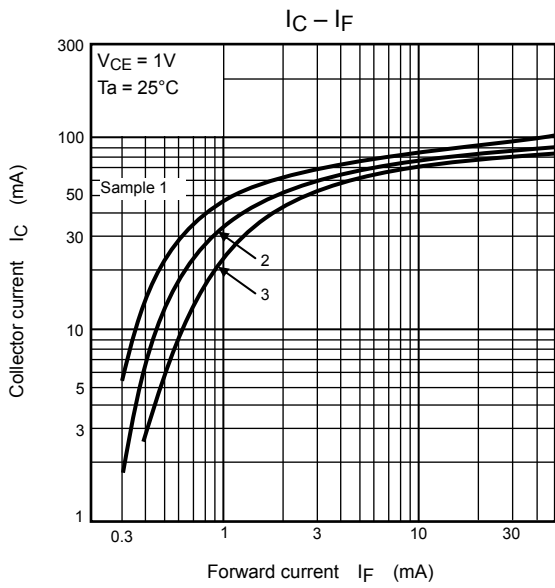
Switching Characteristics (Ta = 25°C)

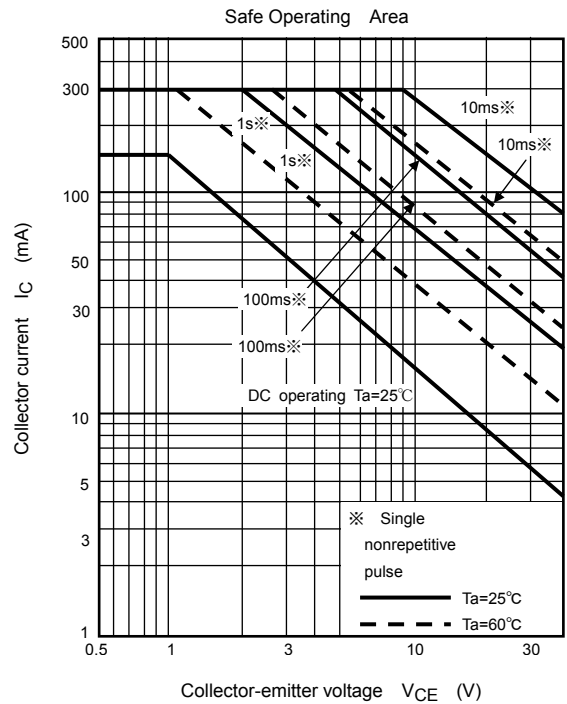
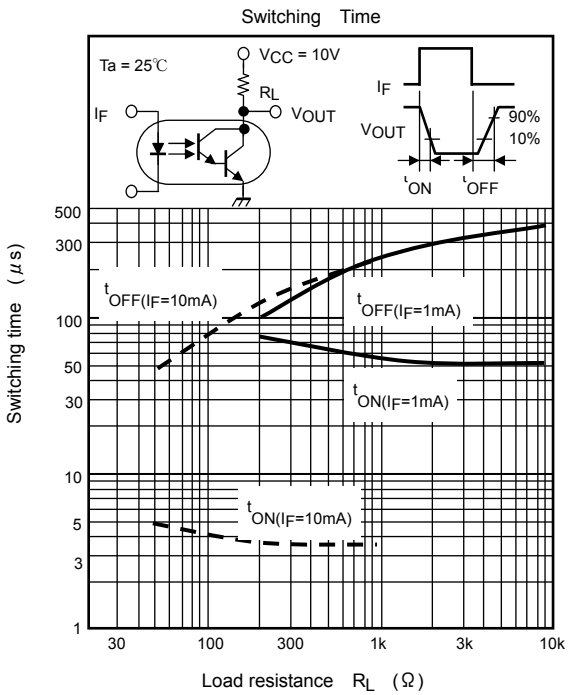
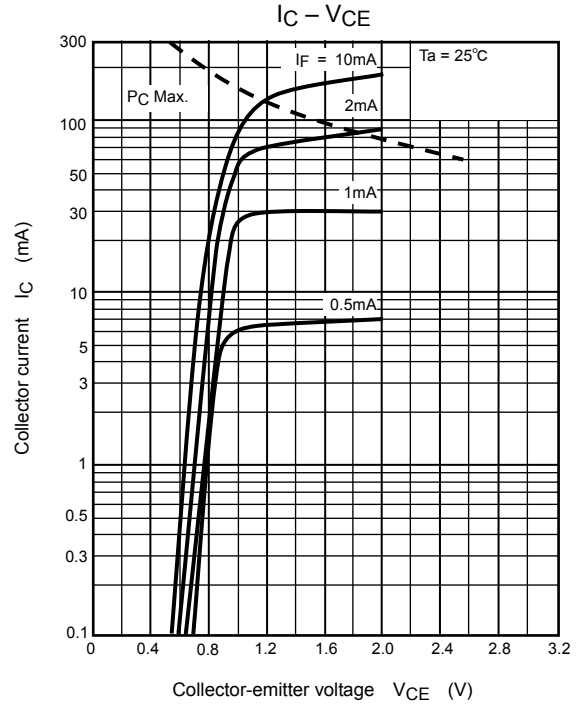
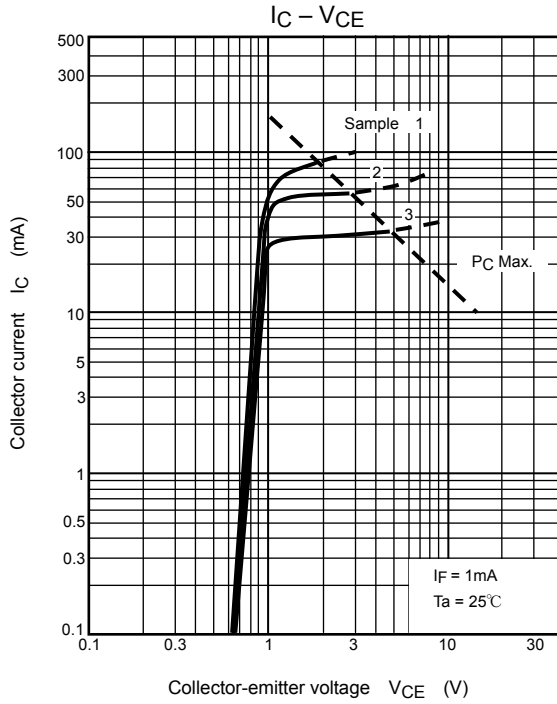
Characteristic	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Turn-on time	t_{ON}	$V_{CC} = 10 \text{ V}, R_L = 180 \Omega$	—	3	—	μs
Turn-off time	t_{OFF}	$I_F = 16 \text{ mA}$	—	80	—	μs

Switching Time Test Circuit









RESTRICTIONS ON PRODUCT USE

20070701-EN

- The information contained herein is subject to change without notice.
- TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property.
In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc.
- The TOSHIBA products listed in this document are intended for usage in general electronics applications (computer, personal equipment, office equipment, measuring equipment, industrial robotics, domestic appliances, etc.). These TOSHIBA products are neither intended nor warranted for usage in equipment that requires extraordinarily high quality and/or reliability or a malfunction or failure of which may cause loss of human life or bodily injury ("Unintended Usage"). Unintended Usage include atomic energy control instruments, airplane or spaceship instruments, transportation instruments, traffic signal instruments, combustion control instruments, medical instruments, all types of safety devices, etc.. Unintended Usage of TOSHIBA products listed in this document shall be made at the customer's own risk.
- The products described in this document shall not be used or embedded to any downstream products of which manufacture, use and/or sale are prohibited under any applicable laws and regulations.
- The information contained herein is presented only as a guide for the applications of our products. No responsibility is assumed by TOSHIBA for any infringements of patents or other rights of the third parties which may result from its use. No license is granted by implication or otherwise under any patents or other rights of TOSHIBA or the third parties.
- GaAs(Gallium Arsenide) is used in this product. The dust or vapor is harmful to the human body. Do not break, cut, crush or dissolve chemically.
- Please contact your sales representative for product-by-product details in this document regarding RoHS compatibility. Please use these products in this document in compliance with all applicable laws and regulations that regulate the inclusion or use of controlled substances. Toshiba assumes no liability for damage or losses occurring as a result of noncompliance with applicable laws and regulations.